

## SINTERED GLASS JUNCTION AVALANCHE RECTIFIER

Reverse Voltage - 1500 V Forward Current - 2.0 A

# 2.1.014(26) min. 1.014(26) min. 1.014(26) min. 1.014(26) min. 0.032(0.82) max.

Dimensions in inches and (millimeters)

## **FEATURE**

Glass passivated High maximum operating temperature Low leakage current Excellent stability

# **MECHANICAL DATA**

Case: SOD-57 sintered glass case

Terminal: Plated axial leads solderable per MIL-STD 202E,

method 208C

Polarity: color band denotes cathode end

Mounting position: any

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

		SYMBOL	BY448	units
Maximun Repetitive Peak Reverse Voltage		Vrrm	1500	V
Maximum RMS Voltage		Vrms	1050	V
Maximum DC blocking Voltage		Vdc	1500	V
Maximum Average Forward Rectified Current		If(av)	2.0	А
Non-Repetitive Peak Forward Surge Current at tp=10ms half sinewave		Ifsm	30.0	А
Maximum Instantaneous Forward Voltage at 3.0A		Vf	1.60	V
Maximum DC Reverse Current at rated DC blocking voltage	Ta =25°C Ta =150°C	Ir	5.0 150.0	μА
Typical Reverse Recovery Time	(Note 1)	Trr	2000	nS
Typical Thermal Resistance	(Note 2)	Rth(ja)	100	K/W
Storage and Operating Junction Temperature		Tstg, Tj	-65 to +175	°C

### Note:

- 1. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A
- 2. on PC with spacing 25mm





### **RATINGS AND CHARACTERISTIC CURVES**

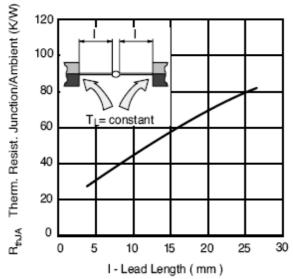


Figure 1. Typ. Thermal Resistance vs. Lead Length

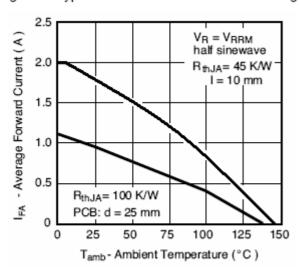


Figure 3. Max. Average Forward Current vs. Ambient Temperature

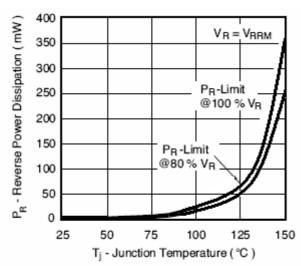


Figure 5. Max. Reverse Power Dissipation vs. Junction Temperature

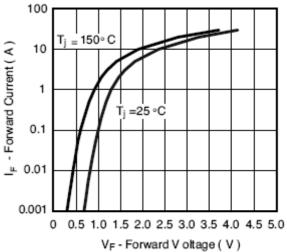


Figure 2. Forward Current vs. Forward Voltage

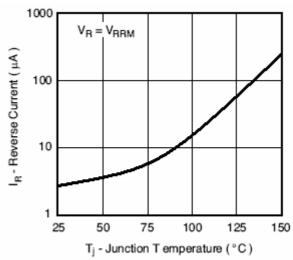


Figure 4. Reverse Current vs. Junction Temperature

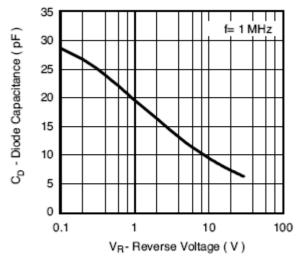


Figure 6. Diode Capacitance vs. Reverse Voltage